Sm eared phase transition in a three-dim ensional Ising model with planar defects:

M onte-C arlo simulations

Rastko Sknepnek and Thomas Vojta Department of Physics, University of Missouri - Rolla, Rolla, MO, 65409

We present results of large-scale M onte C arlo simulations for a three-dimensional Ising model with short range interactions and planar defects, i.e., disorder perfectly correlated in two dimensions. We show that the phase transition in this system is smeared, i.e., there is no single critical temperature, but dienent parts of the system order at dienent temperatures. This is caused by elects similar to but stronger than G rieths phenomena. In an in nite-size sample there is an exponentially small but nite probability to not an arbitrary large region devoid of impurities. Such a rare region can develop true long-range order while the bulk system is still in the disordered phase. We compute the therm odynamic magnetization and its nite-size elects, the local magnetization, and the probability distribution of the ordering temperatures for dierent samples. Our Monte-Carlo results are in good agreement with a recent theory based on extremal statistics.

I. INTRODUCTION

The in uence of disorder on a phase transition is an important and still partially open problem. Historically, the rst attempts to address this question resulted in the belief that any kind of disorder would destroy a critical point because the system would divide itself into regions which independently undergo the phase transition at different temperatures. Therefore, there would not be a unique critical temperature for the system, but the phase transition would be smeared over an interval of temperatures. The singularities of them odynamic quantities, which are the typical sign of a phase transition, would also be smeared (see Ref. 1 and references therein).

However, it soon became clear that this belief was mistaken: in systems with weak short-range correlated disorder the phase transition remains sharp. Harris proposed a simple, heuristic criterion for the in uence of disorder on a critical point: if 2=d, where is the correlation length critical exponent and dithe spatial dimensionality, the disorder does not a ect the critical behavior. In this case, the randomness decreases under coarse graining, and the system electively looks homogeneous on large length scales. The critical behavior is identical to that of the clean system, i.e., the clean renormalization group

xed point is stable against disorder. The relative widths of the probability distributions of the macroscopic observables tend to zero in therm odynamic limit, i.e., they are self-averaging.

Even if the Harris criterion is violated the phase transition will generically remain sharp, but the critical behavior will be dierent from the clean case. There are two possible scenarios, a nite-random ness critical point or an in nite-random ness critical point. A critical point is of nite-random ness type if, under coarse graining, the system stays disordered on all length scales with the eective strength of the random ness approaching a nite constant. The probability distributions of them odynam ic observables reach a nite width in the therm odynam ic limit, i.e., they are not self-averaging. 3,4 From a renormalization group point of view this means there is

a critical xed point with nite disorder strength. At a nite-random ness critical point, the therm odynam ic observables obey standard power-law scaling behavior, but with exponents di erent from the exponents of the corresponding clean system. The other scenario, an in niterandom ness critical point, occurs if the e ective disorder strength in the system grows without lim it under coarse graining. The system looks more and more disordered on larger and larger length scales, i.e., it is described by a renormalization group xed point with in nite disorder. The probability distributions of the therm odynam ic observables become very broad (even on the logarithm ic scale) and their widths diverge when approaching the critical point. The scaling behavior is of activated rather than of conventional power-law type. A fam ous exam ple of an in nite-random ness critical point occurs in the M oc oy-W u m odel, 5,6 a 2d Ising m odel with bond disorder perfectly correlated in one dimension and uncorrelated in the other. Recently, in nite-random ness critical points have also been found in several 1d random quantum spin chains and two-dimensional random quantum Ising models. 7,8,9,10,11,12,13,14

D isorder does not only in uence the physics at the critical point itself, but also produces interesting e ects close to it. These e ects are known as Gri ths phenomena, a topic that has regained considerable attention in recent years. Gri ths phenom ena are non-perturbative effects produced by rare disorder uctuations close to a phase transition. They can be understood as follows: G enerically, the critical tem perature $T_{\rm c}$ of a disordered system is lower than its clean value, T_c^0 . In the tem perature interval T_c < T < T_c^0 , the bulk system is in the disordered phase. On the other hand, in an in nite size sample, there is an exponentially small, but nite probability for nding an arbitrary large region devoid of impurities. Such a region, a 'Gri the island', can develop local order while the bulk system is still disordered. Due to its size, such an island will have very slow dynam ics because ipping it requires changing of the order param eter over a large volum e, which is a slow process. Gri ths¹⁵ showed that the presence of the locally ordered

islands produces an essential singularity 15,16 in the free energy in the whole region $T_{\rm c} < T < T_{\rm c}^{\,0}$, which is now known as the G ri. ths region or the G ri. ths phase 17 In generic classical system s the G ri. ths singularity is weak, and it does not signicantly contribute to the therm odynam ic observables. In contrast, the long-time dynam ics is dominated by these rare regions. Inside the G ri. ths phase the spin autocorrelation function C (t) decays as lnC (t) (lnt) for Ising system s^{17,18,19,20,21} and as lnC (t) t^{-2} for Heisenberg system s^{20,22} These results were recently conmed by more rigorous calculation for the equilibrium 23,24 and dynam ic 25,26 properties of disordered Ising system s.

There are numerous systems where the disorder is

not point like, but is realized through, e.g., dislocations or grain boundaries. This extended disorder in a d-

dim ensional system can often be modeled by defects perfectly correlated in do dimensions and uncorrelated in the remaining $d_2 = d$ dedimensions. It is generally agreed that extended disorder will have even stronger e ects on a phase transition than point-like impurities. Nevertheless, the fate of the transition in the presence of the extended im purities is not settled. Early renormalization group analysis²⁷ based on a single expansion in d did not produce a critical xed point, leading to the conclusion that the phase transition is either smeared or of rst order^{28,29} Laterwork^{30,31,32} which included an expansion in the number of correlated dimensions do lead to a xed point with conventional power law scaling. Subsequent M onte-C arlo simulations of a 3d Ising model with planar defects provided further support for a sharp phase transition scenario. 33 Notice, however, that the perturbative renorm alization group calculations m issed all e ects coming form the rare regions. These e ects were extensively studied for the above-mentioned M cCoy-W u m odel. W hile it was believed for a long time that the phase transition in this model is smeared, it was later found to be sharp, but of in nite-random ness type.9,11,34 Based on these ndings, there was a general belief that a phase transition will remain sharp even in

Recently, it has been shown that this belief is not true. A theory 35,36 based on extrem alstatistics arguments has predicted that impurities correlated in a succiently high number of dimensions will generically smear the phase transition. The predictions of this theory were consmed in simulations of mean—eld type model 35,36 but up to now, a demonstration of the smearing in a more realistic short-range model has been missing.

the presence of extended disorder.

In this paper, we therefore present results of large-scale M onte-C arlo simulations for a 3d Ising modelwith planar defects and nearest-neighbor interactions in both the correlated and uncorrelated dimensions. These simulations show that the sharp phase transition is indeed destroyed by the extended disorder. The smearing of the transition is a consequence of a mechanism similar to but stronger than the Gri ths phenomena. In an Ising system with planar defects true static long-range order can develop on

rare islands devoid of impurities. As a consequence, the order parameter becomes spatially very inhomogeneous and its average develops an exponential dependence on temperature. This paper is organized as follows. In section II, the model is introduced and the mechanism of the smearing is explained. Section III is devoted to the results of the Monte-Carlo simulations and a comparison with the theoretical predictions. In Section IV, we present our conclusions and discuss a number of open questions.

II. THE MODEL

A. 3D Ising model with planar defects

Our starting point is a 3d Ising model with planar defects. Classical Ising spins $S_{ijk} = 1$ reside on a cubic lattice. They interact via nearest-neighbor interactions. In the clean system all interactions are identical and have the value J. The defects are modeled via 'weak' bonds random ly distributed in one dimension (uncorrelated direction). The bonds in the remaining two dimensions (correlated directions) remain equal to J. The system electively consists of blocks separated by parallel planes of weak bonds. Thus, $d_{\rm P}=1$ and $d_{\rm C}=2$. The Hamiltonian of the system is given by:

where $L_{\,?}$ ($L_{\,\text{C}}$) is the length in the uncorrelated (correlated) direction, i, j and k are integers counting the sites of the cubic lattice, J is the coupling constant in the correlated directions and J_{i} is the random coupling constant in the uncorrelated direction. The J_{i} are drawn from a binary distribution:

characterized by the concentration p and the relative strength c of the weak bonds (0 < c 1). The fact that one can independently vary concentration and strength of the defects in an easy way is the main advantage of this binary disorder distribution. However, it also has unwanted consequences, viz. log-periodic oscillations of many observables as functions of the distance from the critical point. These oscillations are special to the binary distribution and unrelated to the smearing considered here; we will not discuss them further. The order parameter of the magnetic phase transition is the total magnetization:

$$m = \frac{1}{V} \sum_{\substack{i;j;k\\i\neq j}}^{X} hS_{i;j;k} i;$$
 (3)

where $V = L_2 L_C^2$ is the volume of the system, and hai is L_2 containing only strong bonds is, up to pre-exponential the therm odynam ic average.

Now we consider the e ects of rare disorder uctuations in the system. Similarly to the Gri ths phenomena, there is a small but nite probability to nd a large spatial region containing only strong bonds in the uncorrelated direction. Such a rare region can locally be in the ordered state while the bulk system is still in the disordered (param agnetic) phase. The ferrom agnetic order on the largest rare regions starts to emerge right below the clean critical temperature $T_{\rm c}^{\,0}$. Since the defects in the system are planar, these rare regions are in nite in the two correlated dimensions but nite in the uncorrelated direction. This makes a crucial di erence compared to systems with uncorrelated disorder, where rare regions are of nite extension. In our system, each rare region is equivalent to a two dimensional Ising system that can undergo a realphase transition independently of the rest of the system. Thus, each rare region can independently develop true static order with a non-zero static value of the local magnetization. Once the static order has developed, the magnetizations of dierent rare regions can be aligned by an in nitesimally small interaction or external eld. The resulting phase transition will thus be markedly di erent from a conventional continuous phase transition. At a conventional transition, a non-zero order param eter develops as a collective e ect of the entire system which is signied by a diverging correlation length of the order param eter uctuations at the critical point. In contrast, in a system with planar defects, dierent parts of the system (in the uncorrelated direction) will order independently, at di erent tem peratures. Therefore the global order will develop inhom ogeneously and the correlation length in the uncorrelated direction will remain nite at all tem peratures. This de nes a smeared transition. Thus we conclude that planar defects destroy a

sharp phase transition and lead to its smearing.

B. Results of extrem al statistics theory

In this subsection we brie y sum marize the results of the extrem al statistics theory³⁶ for the behavior in the 'tail' of the sm eared transition, i.e., in the param eter region where a few rare regions have developed static order but their density is still su ciently low so they can be considered as independent. The approach is very similar to that of Lifshitz³⁸ and others developed for the description of the tails in the electronic density of states. The extremal statistics theory³⁶ correctly describes the leading (exponential) behavior of the magnetization and other observables. A calculation of pre-exponential factors would be much more complicated because one would have to include, am ong other things, details of the geom etry of the rare regions, surface critical behavior 39,40 at the surfaces of the rare regions, and corrections to nite-size scaling. This is beyond the scope of the present paper.

The probability w to nd a large region of linear size

factors:

$$w (1 p^{L})^{?} = e^{\log(1 p)L_{?}} (4)$$

As discussed in subsection IIA, such a rare region develops static long-range (ferrom agnetic) order at som e reduced temperature Tc (L?) below the clean critical reduced tem perature $T_{\text{c}}^{\,0}$. The value of T_{c} (L $_{?}$) varies with the length of the rare region; the longest islands will develop long-rage order closest to the clean critical point. A rare region is equivalent to a slab of the clean system, we can thus use nite size scaling to obtain:

$$T_c^0$$
 $T_c(L) = \frac{1}{2}c(L)j = AL$; (5)

is the nite-size scaling shift exponent of the clean system and A is the amplitude for the crossover from three dimensions to a slab geometry in nite in two (correlated) dim ension but with nite length in the third (uncorrelated) direction. The reduced temperature T_c^0 m easures the distance form the clean critical point. Since the clean 3d Ising model is below its upper critical dim ension $(d_c^+ = 4)$, hyperscaling is valid and the nite-size shift exponent = 1 = .0 combining (4) and (5) we get the probability for nding an island of length Le which becomes critical at somet as:

$$w(t_c) = e^{B \dot{t}_c j}$$
 (for $t_c ! 0$) (6)

with the constant B = log(1 p)A. The total (average) m agnetization m at some reduced temperature t is obtained by integrating over all rare regions which have t_c > t. Since the functional dependence on t of the local magnetization on the island is of power-law type it does not enter the leading exponentials but only preexponential factors, so:

$$m (t) e^{B tj} (fort! 0):$$
 (7)

Now we turn our attention to the hom ogeneous magnetic susceptibility. It contains two contributions, one coming from the islands on the verge of ordering and one from the bulk system still deep in the disordered phase. The bulk system provides a nite, non-critical background susceptibility throughout the whole tail region of the sm eared transition. In order to estimate the second part of the susceptibility, i.e., the part coming from the islands consider the onset of local magnetization at the clean critical point. Using eq. (6) for the density of islands we can estimate:

$$R_0$$
 dtt e Bt (fort! 0): (8)

The last integral is nite because the exponentially decreasing island density overcomes the power-law divergence of the susceptibility of an individual island. Here

is the clean susceptibility exponent and is related to a lower cuto for the island size. Once the rst island is ordered it produces an e ective background magnetic eld which cuts o any possible divergence in . Therefore, we conclude that the hom ogeneous magnetic susceptibility does not diverge anywhere in the tail of the smeared transition. However, there is an essential singularity at the clean critical temperature produced by the vanishing density of ordered islands. Because if this singularity one might be tempted to call this temperature the transition temperature of our system, but this is not appropriate because at this temperature only an in nitesimally small part of the system starts to develop a nite magnetization while most of the system remains solidly in the nonmagnetic phase. We rather view the clean critical temperature as the onset of the smearing region in our model. The system is a simple of the system in our model.

The spatial distribution of the magnetization in the tail region of the smeared transition is very inhom ogeneous. On the already ordered islands, the local (layer) magnetization m $_i$ = (1=L $_{\rm C}^2$) $_{\rm j,k}\,hS_{i;j;k}\,i$ is comparable to the magnetization of the clean system . On the other hand, far away from the ordered islands m $_i$ decays exponentially with the distance from the closest one. The probability distribution of the logarithm of the magnetization P [logm $_i$] will therefore be very broad, ranging from logm $_i$ = O(1) on the largest islands to logm $_t$! 1 on sites very far away from any ordered islands. The typical magnetization m $_{\rm typ}$ can be estimated from the typical distance of a point from the nearest ordered island . U sing eq. (6) we get:

$$x_{typ}$$
 $e^{\beta jtj}$: (9)

At the distance $\boldsymbol{x}_{\text{typ}}$ from an ordered island, the local magnetization has decayed to

$$m_{typ} \quad e^{x_{typ}=0} \quad e^{C e^{B jtj}}$$
 (10)

where $_0$ is the bulk correlation length, which is nite and changes slow by throughout the tail region of the sm eared transition, and C is a constant. A comparison with eq. (7) gives the relation between m $_{\rm typ}$ and the therm odynam ic order param eter (m agnetization) m as:

$$j\log m_{typ}j = \frac{1}{m}$$
: (11)

Thus, m $_{typ}$ decays exponentially with m indicating an extremely broad order parameter distribution. In order to determ ine the functional form of the local order parameter distribution, rst consider a situation with just a single ordered island at the origin of the coordinate system . For large distances x, the local magnetization falls o exponentially as m (x) = m_0 e $^{x=0}$. The probability distribution of y = $\log [n_0(x)] = \log m_0(x)$ as $m_0(x) = \log m_0(x)$.

$$P(\dot{y}) = \frac{dN}{dy} = \frac{dN}{dx} \frac{dx}{dy} = 0 \frac{dN}{dx} \qquad 0$$
 (12)

where dN is the number of sites at a distance from the origin between x and x+dx or, equivalently, having a logarithm of the local magnetization between y and y+dy.

Therefore, for large distances, the probability distribution of logm (x) generated by a single ordered island takes the form

$$P [log(m)] = const: (form (x) 1): (13)$$

In the tail region of the sm eared transition our system consists of a few ordered islands whose distance is large compared to $_0$. The probability distribution of the local magnetization, $\log (m_i)$, thus takes the form (13) with a lower cuto corresponding to the typical island—island distance and an upper cuto corresponding to a distance $_0$ from an ordered island.

C. Finite-size e ects

It is important to distinguish elects of a nite size L_2 in the correlated directions and a nite size L_2 in the uncorrelated directions. If L_2 is nite but L_C is in nite static order on the rare regions can still develop. In this case, the sample contains only a nite number of islands of a certain size. As long as the number of relevant islands is large, nite size—elects are small and governed by the central limit theorem. However, for tellower, we have and rare islands are responsible for the order parameter. The number N of islands which order at the behaves like N L_2 w(t). When N becomes of order one, strong sample-to-sample uctuations arise. Using (6) for w(t) we not that strong sample to sample uctuations start at

$$f_L j = \frac{1}{B} \log (L_?)$$
 : (14)

Thus, nite size e ects are suppressed only logarithm i-cally.

A nalogously, one can study the onset of static order in a sam ple of nite size $L_{\rm ?}$ (i.e., the ordering tem perature of the largest rare region in this sam ple). For small sam ple size $L_{\rm ?}$, the probability distribution P ($T_{\rm s}$) of the sam ple ordering tem peratures $T_{\rm s}$ will be broad because some sam ples do not contain any large islands. With increasing sam ple size the distribution becomes narrower and moves toward the clean $T_{\rm c}^{\,0}$ because more sam ples contain large islands. The maximum $T_{\rm s}$ coincides with $T_{\rm c}^{\,0}$ corresponding to a sam ple without in purities. The lower cuto corresponds to an island size so small that essentially every sam ple contains at least one of them . Consequently, the width of the distribution of critical temperatures in nite-size samples is governed by the same relation as the onset of the uctuations,

$$T_s = \frac{1}{B} \log(L_2)$$
 : (15)

For the system under study in this paper, a nite size in the correlated direction has far less interesting consequences. In this case the rare regions are nite in all directions and cannot develop true static order. Therefore,

the phase transition is rounded by conventional nitesize e ects in addition to the disorder induced smearing discussed in this paper.

III. NUMERICAL RESULTS

A. The method

We now turn to the main part of the paper, Monte-Carlo simulations of a 3d Ising model with planar bond defects and short range interactions, as given in eq. (1). The simulations are performed using the Wol cluster algorithm 41

As discussed above, the smearing of the transition is a result of exponentially rare events. Therefore su ciently large system sizes are required in order to observe it. We have simulated system sizes ranging from $L_{?}$ = 50 to $L_{?}$ = 200 in the uncorrelated direction and from $L_C = 50$ to $L_C = 400$ in the remaining two correlated directions, with the largest system simulated having a total of 32 m illion spins. We have chosen J = 1 and c = 0:1 in the eq. (2), i.e., the strength of a 'weak' bond is 10% of the strength of a strong bond. The simulations have been perform ed for various disorder concentrations p = f0.2;0.25;0.3q. The values for concentration p and strength c of the weak bonds have been chosen in order to observe the desired behavior over a su ciently broad interval of tem peratures. This issue will be discussed in m ore detail in Section IV. The tem perature range has been T = 4:325 to T = 4:525, close to the critical tem perature of the clean 3d Ising model $T_c^0 = 4.511$.

M onte-Carlo simulations of disordered systems require a huge computationale ort. For optimal performance one must thus carefully choose the number N $_{\rm S}$ of disorder realizations (i.e., samples) and the number N $_{\rm I}$ of measurements during the simulation of each sample. Assuming full statistical independence between dierent measurements (quite possible with a cluster update), the variance $_{\rm T}^2$ of the nalresult (thermodynamically and disorder averaged) for a particular observable is given by 43,44

$$_{T}^{2} = \left(\begin{smallmatrix} 2 \\ S \end{smallmatrix} + \begin{smallmatrix} 2 \\ T \end{smallmatrix} = N_{I} \right) = N_{S}$$
 (16)

where $_{\rm S}$ is the disorder-induced variance between sam-ples and $_{\rm I}$ is the variance of measurements within each sample. Since the computational e ort is roughly proportional to N $_{\rm I}$ N $_{\rm S}$ (neglecting equilibration for the moment), it is then clear that the optimum value of N $_{\rm I}$ is very small. One might even be tempted to measure only once per sample. On the other hand, with too short measurement runs most computer time would be spent on equilibration.

In order to balance these requirem ents we have used a large number N $_{\rm S}$ of disorder realizations, ranging from 30 to 780, depending on the system size and rather short runs of 100 M onte-C arb sweeps, with measurements taken after every sweep. (A sweep is dened by a

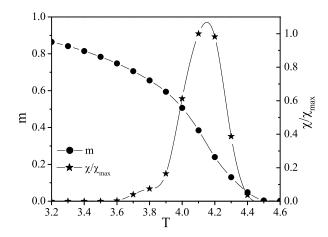


FIG. 1: A verage m agnetization m and susceptibility (spline t) as functions of T for $L_{\rm P}=100$, $L_{\rm C}=200$ and p=0.2 averaged over 200 disorder realizations.

number of cluster ips so that the total number of ipped spins is equal to the number of sites, i.e., on the average each spin is ipped once per sweep.) The length of the equilibration period for each sample is also 100 M onte-C arlo sweeps. The actual equilibration times have typically been of the order of 10-20 sweeps at maximum. Thus, an equilibration period of 100 sweeps is more than su cient.

B. Total magnetization and susceptibility

In this subsection we present num erical results for the total m agnetization m (as usual, our M onte-C arlo estim atorofm is the average of the absolute value of them agnetization in each measurement) and the homogeneous = @m =@h. Fig. 1 gives an overview susceptibility of total magnetization and susceptibility as functions of tem perature averaged over 200 sam ples of size $L_2 = 100$ and $L_C = 200$ with an impurity concentration p = 0.2. We note that at the st glance the transition looks like a sharp phase transition with a critical temperature between T = 4:3 and T = 4:4, rounded by conventional nite size e ects. In order to distinguish this conventional scenario from the disorder induced smearing of section II, we have perform ed a detailed analysis of the system in a tem perature range in the imm ediate vicinity of the clean critical tem perature $T_c^0 = 4:511$.

In Fig. 2, we plot the logarithm of the total magnetization vs. f_c^0 T j averaged over 240 samples for system size L = 200, L_C = 280 and three disorder concentrations p = f02;025;03g. The standard deviation of the total magnetization is below 10 3 . For all three concentrations the data follow the analytical prediction, eq. (7), overmore than an order of magnitude in m with the exponent for the clean Ising model = 0:627. The

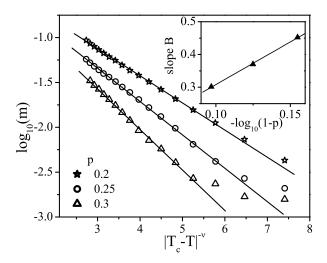


FIG. 2: Logarithm of the total magnetization m as a function of ${\rm JT_c}^0$ T j (= 0:627) for several impurity concentrations p = 0.2;0.25;0.3, averaged over 240 disorder realizations. System size L_? = 200, L_C = 280. The statistical errors are smaller than a symbol size for all \log_{10} (m) > 2:5. Inset: Decay slope B as a function of $\log(1\ p)$.

deviation from the straight line for smallm is due to the conventional nite size e ects (see discussion in subsection IIIC). In the inset we show that the decay constant B depends linearly on $\log(1 - p)$. This is the behavior expected from eq. (4).

C. Finite size e ects and sam ple-to-sam ple uctuations

As discussed in subsection IIC one should distinguish between two dierent nite size e ects, i.e., e ects coming form the nite size $I_{\rm C}$ in correlated direction and e ects produced by the nite size $I_{\rm C}$ in uncorrelated direction.

We start with analysis of the nite size e ects in correlated directions, i.e. L_C nite and L_P ! 1. The true static order on the rare regions is destroyed by the nite length of the island in the correlated direction. For our model d₂ = 1 so no true static long range order can develop. The value of m measured in the simulations is thus due to uctuations which are governed by the cen- $V^{1=2}$, where $V = L_2 L_C^2$ tral lim it theorem, i.e., m is the volume of the system. This produces a conventional nite-size rounding responsible for the deviations of m from the exponential law in Fig. 2. In Fig. 3, we investigate this nite-size e ect in more detail. This qure shows the total magnetization mas a function of Tj for system swith xed size in the uncorrelated direction L_2 = 200 and various lengths in the uncorrelated direction, $L_c = 50;70;100;140;200;280;400$. The m agnetization is averaged over 30 to 240 disorder real-

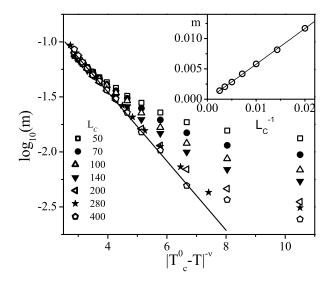
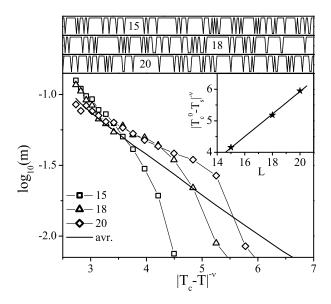


FIG. 3: Logarithm of the totalm agnetization m as a function of ${\rm JT}_{\rm c}^{\,0}$ T j (= 0.627) for disorder concentration p = 0.2 and system sizes L_? = 200, L_C = 50:::400. The statistical errors are smaller than about a symbol size. The solid line shows the analytic prediction, eq. (7). Inset: Total magnetization m as a function of inverse length in the correlated direction L_C for T = 4.5 (${\rm JT}$ T $_{\rm c}^{\,0}$ j = 16:91).

izations. As expected, for high tem peratures, the total m agnetization shows a strong dependence on L_{C} . The sm allest systems follow the exponential behavior (7) only over a narrow range of tem peratures and then cross over to the uctuation determined value. If Ic is increased the crossover between the exponential behavior (7) and the uctuation background shifts to higher tem peratures. In order to show that the uctuation-determ ined value of the total magnetization mat high temperatures indeed follows the predictions of the central lim it theo- $V^{1=2} = (L_2 L_C^2)^{1=2}$ rem, i.e. m $1=L_{C}$ (L_{2} is constant) we plot m as a function of $1=L_{C}$ (T = 45, T_n^0 j = 16:91). The num erical data shown in the inset of Fig. 3 can indeed be well tted with a straight line. These results show that the small-m deviations from the predicted behavior (7) are indeed the result of conventional nite-size rounding.

We now turn our attention to the more interesting nite size elects produced by the nite sample length L in the uncorrelated direction. For suiciently small L? one expects strong sample to sample uctuations, as discussed in subsection IIC. In Fig. 4 we show the logarithm of the total magnetization mas a function of \mathbb{T}_c^0 Tj for three typical disorder realizations. For comparison, the upper panel of the Fig. 4 shows the coupling constant J_i as a function of the position information of three samples. The numbers in the graph indicate the lengths of the longest islands L_i . The system size is $L_i = 200$, $L_C = 280$ with disorder concentration p = 0.2. The solid line is the average magnetization over 240 dis-



order realizations. We see that all three curves qualitatively follow the average at low temperatures but start to deviate form it at higher temperatures. The temperature T_s at which the magnetization of a sample rapidly drops is associated with the ordering of the largest island in this sample. Numerically, we determ in T_s as the tem perature where the sample magnetizations falls below 1=3 of the average magnetization. This de nition contains som e am ount of arbitrariness which corresponds to an overall shift of all $T_{\rm s}$. However, the leading functional dependence of $T_{\text{\tiny S}}$ on the size $L_{\text{\tiny 1}}$ of the longest island in the sample is not in uenced by this shift. In order to dem onstrate this dependence we can apply nite size scaling for the clean 3d Ising model (islands are regions devoid of impurities) in the slab geometry, i.e. on a sample of length Li in one dimension and essentially in nite length in other two dimensions (Lc L_i). In the inset of Fig. 4 we plot T_c^0 T_s j as a function of Li. The data show good agreement with the nite-size scaling prediction. Figure 4 also demonstrates that, in the tail of the sm eared transition (for T ! T_c^0), the average (therm odynam ic) magnetization is determined by rare sam ples with untypically large rare regions.

In Fig. 5, we show the probability distribution of

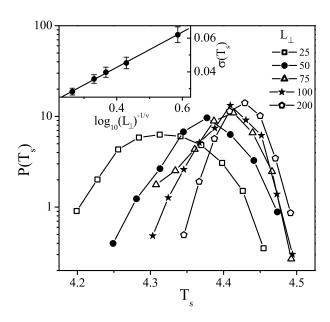


FIG. 5: The probability distribution of sam ple critical tem – perature $T_{\rm s}$ as for di erent sam ple lengths in the uncorrelated direction. The data shown is for system with $L_{\rm ?}=25;50;75;100;200$ and $L_{\rm C}=200$. The probability distribution is calculated from 700 to 780 disorder realizations and disorder concentration p = 0.2. Inset: W idth of the probability distribution as a function of log(L_{\rm ?}) $^{1=}$.

the sam ple ordering temperature T_s for system sizes $L_?=25;50;75;100;200$ and $L_C=200$, computed from 700 to 780 disorder realizations (the statistical error of the T_s values is T_s . 0:03). The results are in good agreement with the predictions of subsection IIC, i.e., the probability distribution of the sample critical temperature becomes narrower and moves toward the clean critical temperature as the sample length $L_?$ in the uncorrelated direction is increased. In the inset of Fig. 5, we show that the width of the probability distribution (de ned as its standard deviation) is proportional to $\log(L_?)^{1=}$ as predicted in eq. (15).

D. Localm agnetization

We now turn to the local (layer) magnetization m $_{\rm i}$ (as for the total magnetization, our Monte-Carlo estimator is the average of the absolute values of the layer magnetizations for each measurement). Close to the clean critical point the system contains a few ordered islands (rare regions devoid of impurities) typically far apart in space. The remaining bulk system is essentially still in the disordered phase. Fig. 6 illustrates such a situation. It displays the local magnetization m $_{\rm i}$ of a particular disorder realization as a function of the position i in the uncorrelated direction for the size $L_{\rm ?}=200$, $L_{\rm C}=200$ at a temperature T=4.425 in the tail of the smeared transi-

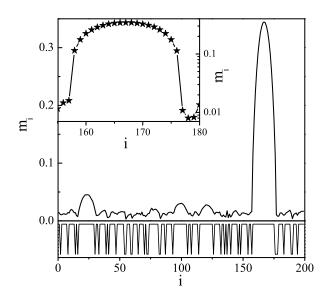


FIG. 6: Local m agnetization m $_{\rm i}$ of a particular disorder realization as a function of the position i in the uncorrelated direction (system size L = 200, $L_{\rm C}$ = 200 and temperature T = 4:425). The statistical error is approximately 5 10 $^{\rm 3}$. Lower panel: The coupling constant $J_{\rm i}$ in the uncorrelated direction as a function of position i. Inset: Log-linear plot of the zoom ed in region in the vicinity of the largest ordered island.

tion. The lower panel shows the local coupling constant J_i as a function of i. The gure shows that a sizable m agnetization has developed on the longest island only (around position i = 160). One can also observe that order starts to em erge on the next longest island located close to i = 25. Far form these islands the system is still in its disordered phase. In the therm odynam ic lim it, the localm agnetization should be exponentially small as predicted by eq. (10). However, in the simulations of a nite size system the local magnetization has a lower cut-o which is produced by nite-size uctuations of the order parameter. These uctuations are governed by the central lim it theorem and can be estimated as $1 = \overline{N}_{cor}$ $L_{cl}^2 = L_C^2$ 5 10 in agreem ent $m_{bu\,lk}$ with the typical o -is land value in Fig. 6. Here, $N_{\rm cor}$ is the number of correlated volumes per slab as determined by the size o the Wol cluster. Let is a typical linear size of a Wol cluster which is, at T = 4.425, I_{cl} In the inset of Fig. 6 we zoom in on the region around the largest island. The local magnetization, plotted on the logarithm ic scale, exhibits a rapid drop-o with the distance from the ordered island. This drop-o suggests a relatively sm all (a few lattice spacings) bulk correlation length 0 in this parameter region.

As was discussed above, nite-size uctuations of the local magnetization far form the ordered islands mask the true asymptotic behavior for very small m $_{\rm i}$. In order to verify the probability distribution (13) of the local

m agnetization num erically, uctuations have to be suppressed su ciently. This would require \sin ulating very large system s whose sizes in the correlated direction increase quadratically with the required magnetization resolution. With sizes available in our \sin ulations we were not able to reproduce the distribution function, eq. (13), of P (\log m $_i$) predicted to be constant at \sin all m $_i$ and calculated for the mean—eld model.

IV. CONCLUSIONS

In this nal section we sum marize our results and discuss how the disorder induced smearing of the phase transition found here compares to the Griths phenomena. We also remark on favorable conditions for observing the disorder-induced smearing in experiments and simulations. Then we shortly discuss dierences between models with discrete and continuous symmetry. We end by brie y addressing the question of smearing of quantum phase transitions.

We have performed large-scale Monte-Carlo simulations of a 3d Ising model with short-ranged, nearest neighbor interactions and planar defects, introduced via correlated bond disorder. The results of the simulations show that the phase transition is not sharp, but rather smeared over a range of temperatures by the presence of the extended defects. The numerical results are in good agreement with the theoretical predictions (see subsection IIB) based on the Lifshitz tail arguments. 35,36

The physics behind the smearing of the phase transition discussed in this paper is similar to the physics underlying Gri ths phenomena. Both e ects are produced by rare spatial regions which are devoid of impurities and therefore locally in the ordered phase while the bulk system is still disordered. The di erence between Gri ths phenomena and disorder-induced smearing is a result of disorder correlations. If the disorder is uncorrelated or short-range correlated, the rare regions have nite size and cannot develop true static order. The order param eter on such a rage region still uctuates, albeit slowly. These slow uctuations lead to the well known Gri ths singularities¹⁵ discussed in section I. In contrast, if the rare regions are in nite in two or more dimensions a stronger e ect arises. The rare regions can develop true static long-range order independently of the rest of the system. The order parameter in such a system develops very inhom ogeneously, which leads to the smearing of the phase transition. Therefore, exactly the same rare regions which would result in Griths phenomena if the disorder was short-range correlated lead to the smeared phase transition in the case of disorder correlated in two or more dimensions. In this sense the smearing of the transition takes the place of both the phase transition and the Gri ths region. Notice that long-range interactions increase the tendency toward smearing. If the interaction in the correlated direction falls o as $1=\hat{r}$ or slower, even linear defects can lead to smearing, because

a 1d Ising model with $1=r^2$ interaction has an ordered phase. 45,46

Now we turn our attention to favorable conditions for observing the smearing in numerical simulations or experiments. This turns out to be controlled by two conditions, one for the concentration of the impurities, and one for their strength. In order to easily observe the smearing, the concentration of rare regions, eq. (6), has to be su ciently large. This requires a relatively small concentration of impurities. If the concentration of the impurities is too high, the exponential drop-o of the island number and thus of misvery steep and the smearing elects would be very hard to observe. On the other hand, if the impurities are too weak, the smeared transition is too close to the clean critical point and the bulk critical point and the bulk critical point and the smearing.

uctuations will e ectively mask the smearing. Consequently, the best param eters for observing the smearing are a small concentration of strong in purities. This has been con med in test calculations using concentrations from p=0.05 to 0.5. Unfavorable parameter values may also be the reason why no smearing has been observed in previous simulations. Specically, in Ref. 33, simulations have been performed using a high concentration p=0.5 of weak in purities (J=J=0.1). The relatively small system sizes (up to L=27) in that simulation were probably not suicient to observe the smearing.

The next remark concerns models with continuous order parameter symmetry. As pointed out above, the smearing of the phase transition is caused by static order on the rare regions. Thus, systems with continuous order parameter symmetry and short-range interactions would exhibit smearing of the phase transition only if the disorder is correlated in three or more dimensions.⁴⁸

Again, long-range interactions increase the tendency toward smearing. It is known⁴⁹ that classical XY and Heisenberg systems in 1d and 2d develop long range order only if the interaction falls om ore slowly than $1=r^{2d}$. Therefore a system with linear (planar) defects would show smearing of the phase transition if the interactions in the correlated direction would fall om ore slowly then $1=r^2$ ($1=r^4$).

We end our discussion with the brief remark about smearing of quantum phase transitions in disordered it inerant electronic systems. Each quantum phase transition can be mapped to a classical phase transition in higher dimension, with imaginary time acting as additional dimension. For dirty it inerant ferromagnets the excive interaction between the spin uctuations in the imaginary time direction falls of as $1=^2$, and the disorder is correlated in this direction. Therefore, the dirty it inerant ferromagnetic transition is smeared even for point-like defects. 36

In conclusion, we have presented results of M onte-Carlo simulations of a 3d Ising model with short-range interactions and planar defects. The numerical results show that the perfect disorder correlations in two dimensions destroy the sharp magnetic phase transition leading to a smeared transition at which the magnetization gradually develops over range of temperatures.

A cknow ledgm ents

We acknowledge support from the University of Missouri Research Board.

G.Grinstein, in Fundam ental Problems in Statistical Mechanics VI, edited by E.G.D.Cohen (Elsevier, New York, 1985).

² A.B.Harris, J.Phys.C 7, 1671 (1974).

³ A. Aharony and A.B. Harris, Phys. Rev. Lett. 77, 3700 (1996).

⁴ S. W isem an and E. Dom any, Phys. Rev. Lett. 81, 22 (1998).

 $^{^5}$ B.M.McCoy and T.T.Wu,Phys.Rev.176,631 (1968).

⁶ B.M.McCoy and T.T.Wu, Phys. Rev. 188, 982 (1969).

⁷ S.K.Ma, C.Dasgupta, and C.-K.Hu, Phys. Rev. Lett. 43, 1434 (1979).

 $^{^{8}}$ R.N.Bhatt and P.A.Lee, Phys.Rev.Lett.48, 344 (1982).

⁹ D.S.Fisher, Phys. Rev. Lett. 69, 534 (1992).

¹⁰ D.S.Fisher, Phys.Rev.B 50, 3799 (1994).

¹¹ D.S.Fisher, Phys.Rev.B 51,6411 (1995).

 $^{^{\}rm 12}$ A.P.Young and H.Rieger, Phys.Rev.B 53,8486 (1996).

¹³ C.Pich, A.P.Young, and N.Kawashima, Phys.Rev.Lett. 81, 5916 (1998).

¹⁴ O. Motrunich, S.-C. Mau, D. A. Huse, and D. S. Fisher, Phys. Rev. B 61, 1160 (2000).

¹⁵ R.B.Gri ths, Phys. Rev. Lett. 23, 17 (1965).

¹⁶ A.J.Bray and D.Huifang, Phys. Rev. B 40, 6980 (1989).

¹⁷ M. Randeria, J. Sethna, and R. G. Palmer, Phys. Rev. Lett. 54, 1321 (1985).

D. Dhar, in Stochastic Processes: Formalism and Applications, edited by D. S. Argawal and S. Dattagapta (Springer, Berlin, 1985).

D. Dhar, M. Randeria, and J. P. Sethna, Europhys. Lett. 5, 485 (1988).

 $^{^{\}rm 20}$ A.J.Bray, Phys.Rev.Lett.60,720 (1988).

A. J. Bray and G. J. Rodgers, Phys. Rev. B 38, 9252 (1988).

²² A.J.Bray, Phys.Rev.Lett.59, 586 (1987).

H. von D reyfus, A.K lein, and J.F. Perez, Com m un.M ath. Phys. 170, 21 (1995).

²⁴ G.G ielis and C.M aes, J. Stat. Phys. 81, 829 (1995).

 $^{^{25}}$ S.Cesi, C.M aes, and F.M artinelli, Commun.M ath.Phys. 189, 135 (1997).

²⁶ S.Cesi, C.M aes, and F.M artinelli, Commun.M ath.Phys. 189, 323 (1997).

²⁷ T.C.Lubensky, Phys. Rev. B 11, 3573 (1975).

²⁸ J.Rudnick, Phys. Rev. B 18, 1406 (1975).

²⁹ D. Andelm an and A. Aharony, Phys. Rev. B 31, 4305 (1975).

 $^{^{\}rm 30}$ S.N.Dorogovtsev, Fiz.Tverd.Tela (Leningrad) 22, 321

- (1980), [Sov. Phys.-Solid State 22,188].
- ³¹ D. Boyanovsky and J. L. Cardy, Phys. Rev. B 26, 154 (1982).
- ³² L.D.Cesare, Phys.Rev.B 49, 11742 (1994).
- ³³ J.C.Lee and R.L.Gibbs, Phys. Rev. B 45, 2217 (1992).
- 34 B.M.McCoy, Phys.Rev.Lett.23, 383 (1969).
- ³⁵ T.Vojta, Phys. Rev. Lett. 90, 107202 (2003).
- ³⁶ T.Vojta, J.Phys.A:Math.Gen.36, 10921 (2003).
- ³⁷ D.Karevskiand L.Turban, J.Phys. A 29, 3461 (1996).
- ³⁸ I.M. Lifshitz, Usp. Fiz. Nauk 83, 617 (1964), [Sov. Phys. Usp. 7 549].
- 39 K. Binder, in Phase Transitions and Critical Phenomena, edited by C. Domb and J. L. Lebowitz (A cademic Press, London, 1983), vol. 8.
- ⁴⁰ H.W. Diehl, in Phase Transitions and Critical Phenomena, edited by C.Domb and J.L.Lebowitz (A cademic Press, London, 1986), vol. 10.
- ⁴¹ U.W ol , Phys. Rev. Lett. 62, 361 (1989).

- W. Selke, L. N. Shchur, and A. L. Tapalov, in Annual Reviews of Computational Physics, edited by D. Stau er (World Scienti c, Singapore, 1994), vol. 1.
- ⁴³ H. G. Ballesteros, L. A. Fernandez, V. Martin-Mayor, A. M. Sudupe, G. Parisi, and J. J. Ruiz-Lorenzo, Phys. Rev. B 58, 2740 (1998).
- ⁴⁴ H. G. Ballesteros, L. A. Fernandez, V. Martin-Mayor, A. M. Sudupe, G. Parisi, and J. J. Ruiz-Lorenzo, Nucl. Phys. B 512, 681 (1998).
- ⁴⁵ D.J.Thouless, Phys. Rev. 187, 732 (1969).
- ⁴⁶ J.Cardy, J.Phys.A 14, 1407 (1981).
- ⁴⁷ B. Berche, P. Berche, F. Igloi, and G. Palagyi, J. Phys. A 31, 5193 (1998).
- 48 N.D.Merm in and H.Wagner, Phys. Rev. Lett. 17, 1133 (1966).
- ⁴⁹ P.Bruno, Phys. Rev. Lett. 87, 137203 (2001).
- ⁵⁰ J.Hertz, Phys.Rev.B 14, 1165 (1976).